Giant pressure-enhancement of multiferroicity in CuBr$_2$

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Type-II multiferroic materials, in which ferroelectric polarization is induced by inversion nonsymmetric magnetic order, promise new and highly efficient multifunctional applications based on the mutual control of magnetic and electric properties. Although this phenomenon has to date been limited to low temperatures, here we report a giant pressure dependence of the multiferroic critical temperature in CuBr$_2$. At 4.5 GPa, $T_C$ is enhanced from 73.5 to 162 K, to our knowledge the highest value yet reported for a nonoxide type-II multiferroic. This growth shows no sign of saturating and the dielectric loss remains small under these high pressures. We establish the structure under pressure and demonstrate a 60% increase in the two-magnon Raman energy scale enhanced from 73.5 to 162 K, to our knowledge the highest value yet reported for a nonoxide type-II multiferroic. This growth shows no sign of saturating and the dielectric loss remains small under these high pressures. We establish the structure under pressure and demonstrate a 60% increase in the two-magnon Raman energy scale up to 3.6 GPa. First-principles structural and magnetic energy calculations provide a quantitative explanation in terms of dramatically pressure-enhanced interactions between CuBr$_2$ chains. These large, pressure-tuned magnetic interactions motivate structural control in cuprous halides as a route to applied high-temperature multiferroicity.

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I. INTRODUCTION

The search for application-suitable multiferroics [1–3] has advanced significantly over the last decade in both type-I and type-II materials [4–9]. Type-I multiferroics [10] have independent magnetic and ferroelectric transitions [11,12], meaning that even when both transition temperatures are high, the magnetoelectric coupling, and hence the scope for mutual control, is usually weak. The physics of most type-II multiferroics [10,13–15] involves frustrating magnetic interactions that give rise to a spiral magnetic order [16], which immediately generates a ferroelectric polarization by the inverse Dzyaloshinskii-Moriya mechanism [17–21]. However, an intrinsic drawback of magnetic frustration is that it suppresses the onset of long-range order, and hence most currently available type-II multiferroics operate only at low temperatures [14].

A generic route to higher operating temperatures in type-II multiferroics is to increase the strength of the magnetic interactions. This can, in principle, be achieved through structural alterations, for which perhaps the cleanest method is an applied pressure [22–26]. Pressure, broadly construed to include chemical pressure and substrate pressure, acts to increase electronic hybridization without introducing disorder. In the most minimal model for a magnetic insulator, the antiferromagnetic (AF) exchange interaction is given by $J = 4t^2/U$, where $t$ is the orbital hybridization and $U$ is the on-site Coulomb repulsion. However, excessive $t$ risks driving the system metallic, thus losing its magnetic and ferroelectric properties. The most scope for achieving large $J$ values is offered by large initial values of both $t$ and $U$, making the spin-1/2 Cu$^{2+}$ ion particularly promising in view of its often strong on-site correlations and significant orbital hybridization with ligands. It is not a coincidence that complex copper oxides become high-temperature superconductors after charge-carriers are introduced into the Mott-insulating parent compounds [27], or that CuO is a type-II multiferroic with the co-highest transition temperature ($T_C \simeq 230$ K) known to date [28].
dielectric-constant, nuclear magnetic resonance (NMR), Raman-scattering, and x-ray diffraction (XRD) measurements in three different types of pressure cells, we have established the \((P, T)\) phase diagram up to pressures of 4.5 GPa. As shown in Fig. 1, we find a rapid and massive pressure-driven enhancement of the multiferroic transition temperature. Density-functional theory (DFT) calculations based on the XRD structure establish that the equally rapid rise of the two-magnon Raman energy is a consequence of the dramatic pressure-sensitivity of the Cu-Br-Br-Cu \(J_1\) interaction, while \(T_N\) and hence \(T_C\) are driven primarily by the interplane coupling (most strongly by \(J_5\)). There is no evidence for saturation of this behavior up to the largest pressures studied, where the material remains highly insulating, confirming that there is plenty of room at the top for pressure tuning of \(T_C\) in CuBr2.

The structure of this article is as follows: In Sec. II we present details of our sample and experimental methods and summarize our theoretical analysis. In Sec. III we present the results of our dielectric measurements in two different types of pressure cell. Section IV shows analogous results for the magnetic properties obtained by NMR and Raman scattering. In Sec. V we analyze our high-pressure structural measurements by detailed first-principles calculations of electronic and magnetic energies, from which we explain the pressure evolution of all of the magnetic interactions governing the behavior of CuBr2. Section VI contains a discussion of our results, some perspective on the prospects they offer for applicable multiferroics, and a brief summary.

**II. MATERIAL AND METHODS**

Large single crystals of CuBr2 were grown by slow evaporation from aqueous solutions [29]. Because ferroelectric transitions usually cause sudden changes in the dielectric constant, we attached two copper-plate electrodes to the opposing \(ab\) faces of a plate-like crystal to form a capacitor with the electric field applied perpendicular to the \(ab\) plane. Measurements of the capacitance as a function of temperature \(T\), pressure \(P\), and magnetic field \(B\) were used to indicate when a spontaneous ferroelectric polarization had developed. Dielectric measurements were performed in a piston cell (PC) using a crystal with dimensions \(4 \times 1.5 \times 0.4 \text{ mm}^3\) and in a cubic anvil cell (CAC) using a crystal with dimensions \(0.7 \times 0.7 \times 0.2 \text{ mm}^3\). The softness and propensity to chemical dissolution of the crystal meant that dielectric measurements above 2.4 GPa were possible only in the CAC, but not yet in anvil cells with smaller sample spaces as reported in the literature [32]; the larger error bars on the corresponding data points in Fig. 1 reflect the complexity of these measurements. The sample and copper plates were connected by using an inert epoxy and suspended in a Teflon capsule filled with Daphne oil as the pressure-transmitting medium. The pressure was calibrated at room temperature by monitoring the characteristic resistance changes of bismuth (Bi). The capacitance was measured by using an Agilent 4263B LCR meter with an excitation level of 1.0 V at 100 kHz.

The zero-field \(^{81}\text{Br}\) \(I = 3/2\) NMR spectra were measured by using the spin-echo method with \(\pi/2-\tau-\pi\) sequences, where \(\pi/2\) and \(\pi\) denote rf pulses with respective
time durations of 0.5 and 0.8 \mu s, and the time interval is \tau = 6 \mu s. The pressure was calibrated by using the \textsuperscript{63}Cu nuclear quadrupole resonance (NQR) frequency of Cu\textsubscript{2}O in the pressure cell [33]. The electronic Raman scattering measurements were performed in a confocal backscattering geometry using the 632.8 nm line of a He-Ne laser. The low-\textit{T} and high-\textit{P} conditions were realized by using an Almax easyLab diamond anvil cell (DAC) integrated into a Janis ST-500 optical cryostat, with argon as the pressure-transmitting medium. The pressure was calibrated by the fluorescence line of a ruby sphere loaded together with the sample inside the DAC. The high-pressure XRD experiments were performed at pressures up to 14.73 GPa at beamline 16 BM-D of the HPCAT sector at the Advanced Photon Source (APS), Argonne National Laboratory, using a Mao-type symmetric DAC. CuBr\textsubscript{2} powder samples and ruby chips were loaded into the sample chamber with Neon gas as the pressure-transmitting medium. Diffraction patterns were recorded on a MAR345 image plate and integrated by DIOPTAS software.

First-principles calculations of the structural and magnetic properties of CuBr\textsubscript{2} were carried out by using density-functional theory with the electronic correlations for the Cu 3d states included at the mean-field level within the generalized gradient approximation (GGA) + U approach. In the first (structural) step, the lattice parameters at selected pressure values were taken from experiment and the internal positions of the Br ions were optimized by using the Vienna \textit{ab initio} simulation package (VASP) [34]. In the second (magnetic) step, the magnetic interaction parameters [Fig. 6(c)] were estimated from the structures at each pressure by computing the total magnetic energies in 27 different spin configurations using the all-electron full-potential local-orbital (FPLO) basis code [35] and then performing a total-energy mapping to a pure Heisenberg model with nine different bilinear parameters \( J_i \) [Fig. 6(a)].

### III. HIGH-PRESSURE DIELECTRIC MEASUREMENTS

The dielectric constant is extracted from the capacitance between two copper plates attached to single crystals, as described in Sec. II. Because the sample dimensions change under pressure, we present the capacitance rather than the dielectric constant. Results from measurements in the PC with no applied magnetic field are shown in Fig. 2(a) and in the CAC in Fig. 2(b). At \( P = 0.05 \text{ GPa}, \) the capacitance at 80 K is 1.07 pF, which gives a dielectric constant \( \varepsilon_r \approx 8.1, \) close to the value reported previously at ambient pressure [29]. The onset of ferroelectricity is shown by a sudden increase in capacitance upon cooling below \( T_C \approx 75 \text{ K}, \) which is slightly higher than the ambient-pressure value, \( T_C \approx 73.5 \text{ K}. \) The capacitance decreases monotonically with further cooling, because of reduced charge fluctuations, and increases with rising pressure, as might be expected upon compression (reduced interlayer separations). The remarkable feature of these data is the dramatic rise of \( T_C \) to 118.5 K at 2.4 GPa in the PC, and further to 162 K at 4.5 GPa in the CAC (Fig. 1). The latter \( T_C \) represents a 120% increase over the ambient-pressure value, or an average growth rate \( dT_C/dP \approx 19.7 \text{ K/GPa}. \) Equally surprisingly, \( T_C \) continues to rise nearly linearly, with no evidence at 4.5 GPa for a saturation of the effect.

To verify the presence of a magnetoelectric coupling, we applied an external magnetic field in the \textit{ab} plane in our PC measurements. This is expected to distort the spiral magnetic structure and hence to affect the ferroelectric properties. As shown in Fig. 3(a), the capacitance at 2.4 GPa in fields \( B = \mu_0 H = 0, 5, \) and 10 T is constant above \( T_C = 118.5 \text{ K}, \) and so is \( T_C \) itself. However, the magnitudes of both the capacitance and the capacitance anomaly increase monotonically with decreasing field, providing direct evidence both for a significant magnetoelectric coupling and for magnetic-order-induced (i.e., type-II) ferroelectricity [29].

The dielectric loss \( \tan \delta \) is an important figure of merit for the practical application of ferroelectric materials. In Fig. 3(b) we observe that \( \tan \delta = 0.013 \pm 0.001 \) above \( T_C \) at all pressures reached in the PC; this value is again consistent with ambient-pressure data [29]. At all pressures, \( \tan \delta \) increases weakly when the sample is cooled below \( T_C, \) forming a broad low-\textit{T} peak whose center scales with \( T_C. \) Although we do not fully understand the origin of this feature, one possibility is that the spiral spin configuration continues to fluctuate until
the sample is cooled substantially below \( T_C \), allowing for a dissipation of electrical energy into the spin system through the magnetoelectric coupling. These very small values of \( \tan \delta \) at all pressures nonetheless constitute an extremely low dielectric loss, reflecting both the strongly insulating nature of \( \text{CuBr}_2 \), at least up to 2.5 GPa, and the considerable potential for device applications.

IV. HIGH-PRESSURE NMR AND RAMAN SCATTERING MEASUREMENTS

We have probed the magnetic system by zero-field NMR and Raman-scattering measurements performed over the same range of pressures as our dielectric measurements. The \( ^{81}\text{Br} \) NMR spectra at all temperatures and pressures, shown in Fig. 4(a) as the \( T \)-weighted spin-echo intensity as a function of frequency, have one clearly identifiable \( I_{1/2} \leftrightarrow 3/2 \) peak [36] whose position moves systematically with both \( P \) and \( T \). We focus on the resonance frequency, \( f(P, T) \) of this peak at each pressure and display its temperature dependence in Fig. 4(b). Below \( T_N \), \( f(P, T) \) has two additive contributions, one due to the electric-field gradient (EFG), \( f_0(P, T) \), and one from the static local hyperfine field \( A_{hf} \langle S \rangle \) (where \( A_{hf} \) is the hyperfine coupling constant and \( \langle S \rangle \) is the average magnetic moment). The \( f_0 \) term is expected to change very little with temperature at low \( T \), and we find it to increase only rather weakly with pressure. Because the second contribution is proportional to the magnetic order parameter, \( f(P, T) \) decreases sharply as \( T \rightarrow T_N(P) \); a fit to the form \( f(P, T) = f_0(P, T_N) + a(P)(T_N - T)^{1/2} \) at each \( P \) (solid lines) allows us to deduce the values \( T_N(P) \) up to 2.3 GPa shown in Fig. 1. We comment that \( f(P, T) \) tends to saturate below 40 K [Fig. 4(b)], with \( f(P, T) - f_0(P) = 39 \) MHz both at \( P = 0.1 \) GPa and at 2.3 GPa, confirming that the ordered moment changes very little with pressure (under the assumption that \( A_{hf} \) does not change with \( P \)).

The Raman susceptibility is obtained by dividing the recorded scattered photon intensities by the Bose factor. Its dominant feature is the “two-magnon” excitation [37,38], which we show in Fig. 5(a) for all temperatures at a fixed
Despite the complexities inherent to an accurate modeling of the two-magnon response, it is safe to conclude that the relevant magnetic interactions in the system are enhanced massively by the effects of hydrostatic pressure.

A subsidiary piece of information may be extracted from the $T$-dependence of the two-magnon peak intensity, based on the empirical connection between $T_N$ and the intensity increase upon cooling at ambient pressure [38]. In Fig. 5(c), we average the Raman susceptibility over a fixed-percentage energy range [Fig. 5(a)] located slightly above the central energy of the two-magnon peak (in order to avoid multiphonon scattering processes that overlap with the electronic signal at lower energies). This analysis allows us to extract values for $T_N(P)$, marked by the arrows in Fig. 5(c), which again are fully consistent with the values of $T_C(P)$ shown in Fig. 1.

V. HIGH-PRESSURE STRUCTURAL ANALYSIS AND DFT CALCULATIONS

Our data in Figs. 2 and 3 confirm that CuBr$_2$ retains qualitatively the same type-II multiferroic properties at all pressures below 5 GPa. To explain the giant pressure-sensitivity of $T_C$ in a quantitative manner, we investigate the structure of CuBr$_2$ by high-pressure XRD measurements and corresponding DFT calculations. XRD was performed up to 15 GPa using synchrotron radiation at the Advanced Photon Source, as outlined in Sec. II, and we quote the lattice parameters over the full pressure range in Table I. The key features of our results are first that the monoclinic structure is preserved for all pressures and second that, as may be expected to lowest order, the chain units remain rather rigid. There are only small relative changes to the $b$-axis dimension and the angle $\beta$, whereas the $a$ and $c$ lattice parameters, which correspond to the chains being compressed together, change by approximately 12%. We comment that, although one might expect the ionic displacement associated with the ferroelectric transition (inset Fig. 1) to lift the symmetry and interfere with the magnetic interactions, this value turns out to be truly vanishingly small (from the pyroelectric current [29] one may estimate it to be 0.4 fm on each Br$^-$ ion) and hence plays no role in the structure or magnetism of the low-$T$ phase.

Our first-principles calculations under pressure are a two-step process, as described in Sec. II. First we perform a structural optimization at selected experimental pressures by...
FIG. 6. Crystal structure and magnetic interactions under pressure. (a) Crystal structure of CuBr$_2$ viewed nearly parallel to the $b$ axis. The inset displays the structure of two chains lying almost precisely in the $b(a+c)$ plane. The nine Cu-Cu superexchange interactions computed under pressure are indicated. (b) Relative change of the lattice parameters $a$, $b$, and $c$, as well as of the angle $\beta$, determined by XRD at 300 K in a DAC and shown as functions of pressure. The lattice remains in a monoclinic structure at all pressures. The DAC measurements are normalized to the base-pressure dimensions obtained at $P = 0.49$ GPa, $a_0 = 7.09$ Å, $b_0 = 3.47$ Å, $c_0 = 6.91$ Å, and $\beta_0 = 119.3^\circ$. (c) Pressure-dependence of the magnetic interactions $J_i$ deduced from the DFT calculations.

fixing the lattice parameters to those of the corresponding XRD measurements and relaxing the internal ionic positions within the “GGA + $U$” approach. In this type of calculation, reliable results are obtained by using a $k$-point mesh of size $10 \times 10 \times 10$, a plane-wave cutoff energy of 800 eV, and representative Cu-ion correlation parameters $U_{\text{VASP}} = 10$ eV and $J_H = 1$ eV; the crystal structures are relaxed until the calculated forces fall below the threshold $10^{-3} \text{eV/Å}$. For correlated systems, it is in general necessary to include the spin degrees of freedom of the transition-metal cation to ensure reliable structural predictions that, however, are quite insensitive to the actual magnetic order; here a FM order was imposed, which resulted in a total magnetic moment of $1.0 \mu_B$ per formula unit.

For the second step of interpreting the magnetic properties of CuBr$_2$, we identify $i = 9$ significant superexchange paths, $\{J_i\}$, as shown in Fig. 6(a). These span the three spatial dimensions of the system and their values can be expected to determine the physics of the $b$-axis chains, the $b(a+c)$ planes, and 3D magnetic ordering. We then compute the total energies of 27 different magnetic configurations and map these to a Heisenberg model with interaction parameters $J_i$. The magnetic-energy calculations used two different supercells, with dimensions $2 \times 1 \times 2$ and $1 \times 4 \times 2$, and respective $k$-mesh sizes $12 \times 12 \times 12$ and $7 \times 7 \times 7$. Electronic correlations were modeled by using the GGA + $U$ functional with $U = 6$ eV and $J_H = 1$ eV; it is this (FPLO) value of $U$ which has a direct influence on the energy scale of the magnetic interactions. The fit to the spin model was performed by a least-squares regression analysis of the overdetermined system of 27 equations with 11 unknowns (nine superexchange parameters and two nonmagnetic contributions to the total energy, one for each supercell). Calculated $J_i$ values for three representative pressures taken from the XRD study, namely 0.49, 5.65, and 14.73 GPa, are shown in Fig. 6(c). The mean-square total-energy deviation between the $ab$ initio calculation and the spin model was 0.06 meV/Cu for $P = 0.49$ GPa, 0.16 meV/Cu for $P = 5.65$ GPa, and 0.52 meV/Cu for $P = 14.73$ GPa, indicating the reliability of the spin model at all pressures.

Considering first the chain units, clearly $J_1$ and $J_5$ change rather little with pressure, which to lowest order may be expected from the small changes to the $b$-axis lattice parameter [Fig. 6(b)]. In more detail, the FM [41] Cu-Br-Cu $J_1$ interaction is often very sensitive to the bond angle, but here this is found to change by less than $0.5^\circ$ in a regime close to its optimal value [42]. While the AF $J_5$ bond is a Cu-Br-Br-Cu “super-supерexchange” path that also depends on the bond angle, this remains largely fixed by the rigidity of the chains.

The dominant physics of the system occurs in the $b(a+c)$ plane due to $J_7$, which increases from 10 to 18 meV up to 5.65 GPa and then to 35 meV at 14.73 GPa. This giant
TABLE II. Cu-Br distance, $d_{\text{Cu-Br}}$, and Br-Br distances, respectively $d_{\text{Br-Br}}^a$ and $d_{\text{Br-Br}}^c$, for the $J_5$ and $J_7$ paths represented in Fig. 6(a), computed by DFT for pressures of 0.49, 5.65, and 14.73 GPa.

<table>
<thead>
<tr>
<th>$P$ [GPa]</th>
<th>$d_{\text{Cu-Br}}$ [Å]</th>
<th>$d_{\text{Br-Br}}^a$ [Å]</th>
<th>$d_{\text{Br-Br}}^c$ [Å]</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.49</td>
<td>2.440</td>
<td>3.468</td>
<td>3.651</td>
</tr>
<tr>
<td>5.65</td>
<td>2.421</td>
<td>3.423</td>
<td>3.380</td>
</tr>
<tr>
<td>14.73</td>
<td>2.375</td>
<td>3.350</td>
<td>3.123</td>
</tr>
</tbody>
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enhancement actually changes the nature of the planar magnetism from $b$-axis dominated at ambient pressure to spatially isotropic at 5 GPa to $(a+c)$-axis dominated at 15 GPa; however, in the absence of significant frustration it has no effect on the $b$-axis spiral order. The huge rise of $J_7$ under pressure may be understood completely from the fact that it is also a Cu-Br-Br-Cu path, with the same geometry as $J_5$ [Fig. 6(a)], and while the Cu-Br distance and angle are strongly constrained in the chain units, the Br-Br bond in the $(a+c)$ direction takes up most of the unit-cell compression. As Table II makes clear, it shrinks from being 0.18 Å longer than the comparable distance in $J_5$ at 0.49 GPa to 0.23 Å shorter at 14.73 GPa.

Physically, these three interactions create the dominant energy scales in the magnon dispersion, and $J_7$ would account completely for the rapid pressure enhancement observed in the two-magnon Raman signal [Figs. 5(b) and 5(d)]. Our absolute parameter values are controlled by the effective $U$ in the calculations, but in CuBr$_2$ it is difficult to obtain an experimental benchmark due to sample decomposition issues in the measurement of the high-temperature susceptibility [29] and theoretical issues in interpreting the two-magnon Raman energy (Sec. IV). Thus we do not attempt to fit $U$ and simply use a value (6 eV) typical for insulating inorganic Cu systems. Still, $J_1$, $J_3$, and $J_7$ span only two spatial dimensions and to discuss the 3D magnetic order it is necessary to consider the interplane interactions. We find that the second-shortest path in the system, $J_2$, creates a zigzag interchain network in the $ab$ plane, also rises by a factor of five from 0.49 to 5.65 GPa (and a further factor of four to 14.73 GPa). Similar rises can also be found in the slightly weaker $J_3$ and $J_6$ interactions. These results, which are easy to justify by considering the pressure-induced changes to interchain spin density in the $ab$ and $bc$ planes, account for the steep rise in $T_N$, and hence in $T_C$, over the pressure range of Fig. 1. It is clear from our XRD measurements and DFT calculations that this $T_C$ enhancement can continue to far higher pressures, where $J_7$ will also play an increasing role in raising $T_N$, with no intervening structural transition. These results raise the prospect of room-temperature multiferroicity in suitably strained CuBr$_2$.

VI. DISCUSSION AND CONCLUSION

Figure 1 shows that the two intrinsically linked characteristic temperatures $T_C$ and $T_N$, as measured by a range of probes and in a number of different pressure cells, rise strongly with pressure. Figure 5(d) shows a proportionally similar and equally quasi-linear rise in the central energy scale determined by two-magnon Raman scattering. To our knowledge, our maximal $T_C$ of 162 K, achieved at 4.5 GPa in a CAC, is unprecedentedly high for a nonoxide type-II multiferroic. Furthermore, although it remains below that of some oxide type-II multiferroics, such as CuO and YBaCuFeO$_5$ ($T_C \approx$ 230 K [28,43]), many of these suffer from higher dielectric loss due to their semiconducting nature [28,44,45]. The persistence of low dielectric loss in CuBr$_2$ under pressure, despite the increase in orbital hybridization that should move the system towards metallicity, constitutes a major advantage for electronic applications.

We stress that the characteristic magnetic energy scales in CuBr$_2$, reflected in the energy of the two-magnon peak, are much higher than $T_N$. This indicates that both frustration and dimensionality effects play a strong role in suppressing $T_N$ at ambient pressure, and that the effect of pressure is to reduce both. Indeed, our DFT calculations demonstrate that the primary change is caused by the interchain $(a+c)$-axis coupling $J_7$, which enhances the two-dimensional (2D) nature and makes chain frustration less energetically relevant. This said, it is important to note that neither the rising $J_7$ nor any of the other pressure-enhanced interactions has a significant effect on the existence of the in-chain frustration, which creates the helical $b$-axis spin state required for type-II multiferroicity. Beyond $J_7$, we have shown that the interchain $ab$-plane coupling $J_2$ plays the leading role in making the system 3D and hence governs the value of $T_N$. Despite being very low at ambient pressure, its high pressure-sensitivity causes the strong rise of $T_N$ whose lower end we have characterized in the present work. We comment that such massive pressure effects on magnetism are known in Cu-based metal-organic materials [46], due to a combination of soft structures and highly directional ligand paths, but are uncommon in inorganic Cu systems and, to date, unknown in multiferroic systems.

In summary, we have demonstrated how strongly the magnetic interactions in CuBr$_2$ are changed by pressure, and how this makes it possible to effect a giant enhancement of the multiferroic $T_C$ by using any available methods for structural control. Dielectric investigations of CuBr$_2$ at pressures higher than our current limit of 4.5 GPa are certainly required. Alternatively, different methods of structural tuning, including chemical pressure [47] and epitaxial stress [48], also affect the magnetism of low-dimensional systems in ways similar to a hydrostatic pressure. Thin-film growth with epitaxial stress applied along the $a$ or $c$ direction, by the choice of a suitable substrate, should be a particularly valuable route to higher $T_C$ values in CuBr$_2$. We conclude by stressing once again that the pressures we have investigated remain far from saturating the $T_C$ increase in CuBr$_2$, and that they seem not to impair any of the significant magnetoelectric coupling, the dielectric loss, or the insulating properties of the material, all of which present major technical advantages for application purposes.

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